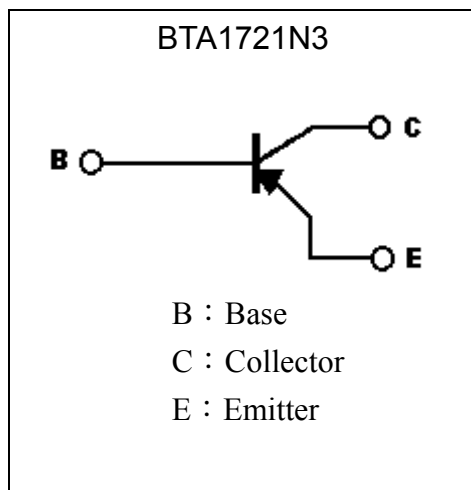
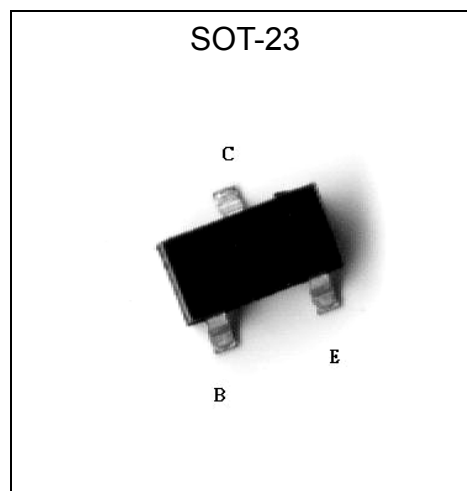


General Purpose PNP Epitaxial Planar Transistor

BTA1721N3

Description

- High breakdown voltage.
- Low collector output capacitance.
- Ideal for chroma circuit.
- Pb-free package

Symbol

Outline

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V _{CB0}	-300	V
Collector-Emitter Voltage	V _{CEO}	-300	V
Emitter-Base Voltage	V _{EB0}	-5	V
Collector Current	I _C	-500	mA
Power Dissipation	P _d	225	mW
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55~+150	°C



Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	-300	-	-	V	$I_C = -100\mu A$
BV_{CEO}	-300	-	-	V	$I_C = -1mA$
BV_{EBO}	-5	-	-	V	$I_E = -100\mu A$
I_{CBO}	-	-	-0.25	μA	$V_{CB} = -200V$
I_{EBO}	-	-	-0.1	μA	$V_{EB} = -3V$
* $V_{CE(sat)}$	-	-	-0.5	V	$I_C = -20mA, I_B = -2mA$
* $V_{BE(sat)}$	-	-	-0.9	V	$I_C = -20mA, I_B = -2mA$
* h_{FE}	25	-	-	-	$V_{CE} = -10V, I_C = -1mA$
* h_{FE}	52	-	270	-	$V_{CE} = -10V, I_C = -10mA$
* h_{FE}	25	-	-	-	$V_{CE} = -10V, I_C = -30mA$
f_T	50	-	-	MHz	$V_{CE} = -20V, I_C = -10mA, f = 100MHz$
Cob	-	-	6	pF	$V_{CB} = -20V, f = 1MHz$

*Pulse Test: Pulse Width $\leq 380\mu s$, Duty Cycle $\leq 2\%$

Classification Of h_{FE}

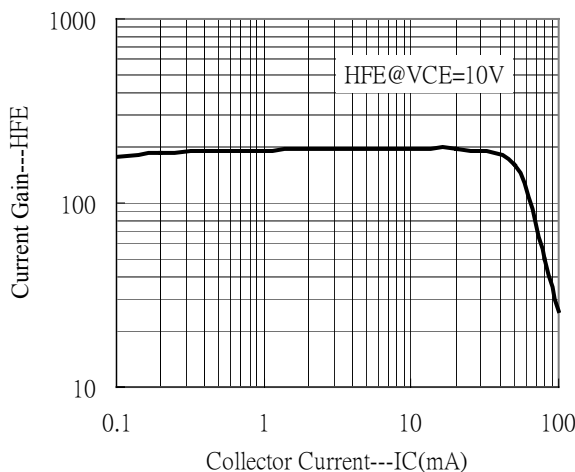
Rank	K	P	Q
Range	52~120	82~180	120~270

Ordering Information

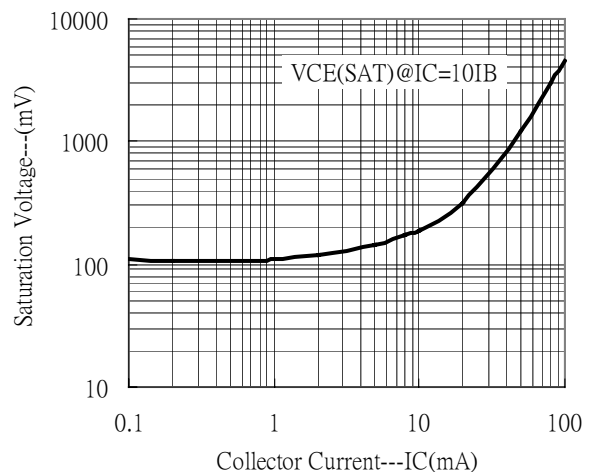
Device	Package	Shipping	Marking
BTA1721N3	SOT-23 (Pb-free)	3000 pcs / Tape & Reel	2D

Characteristic Curves

Current Gain vs Collector Current

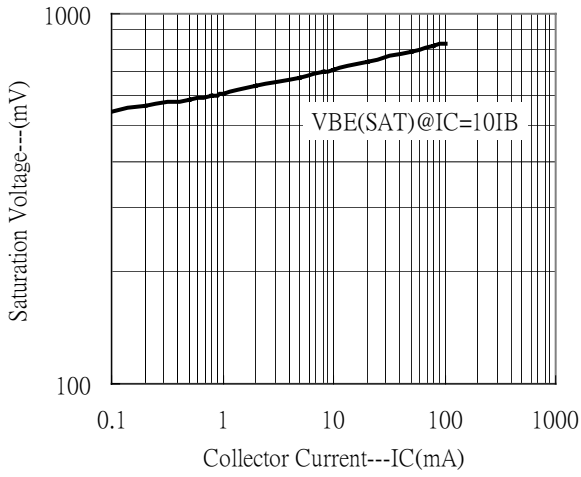


Saturation Voltage vs Collector Current

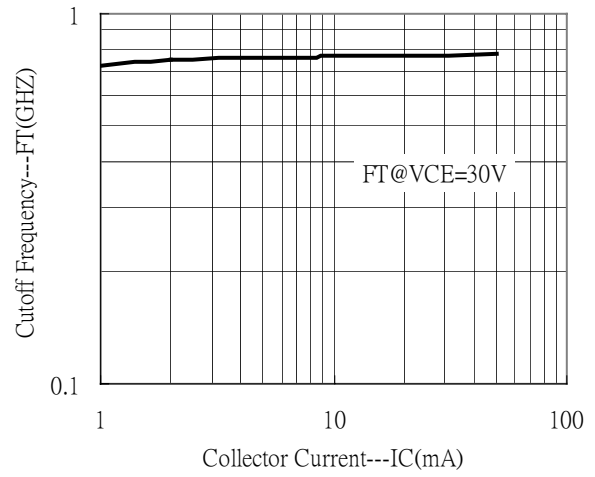




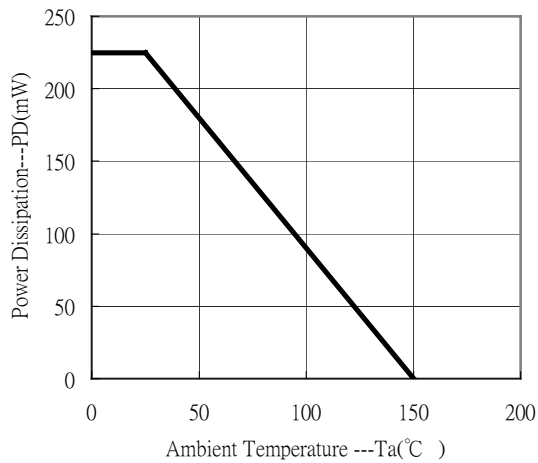
Saturation Voltage vs Collector Current



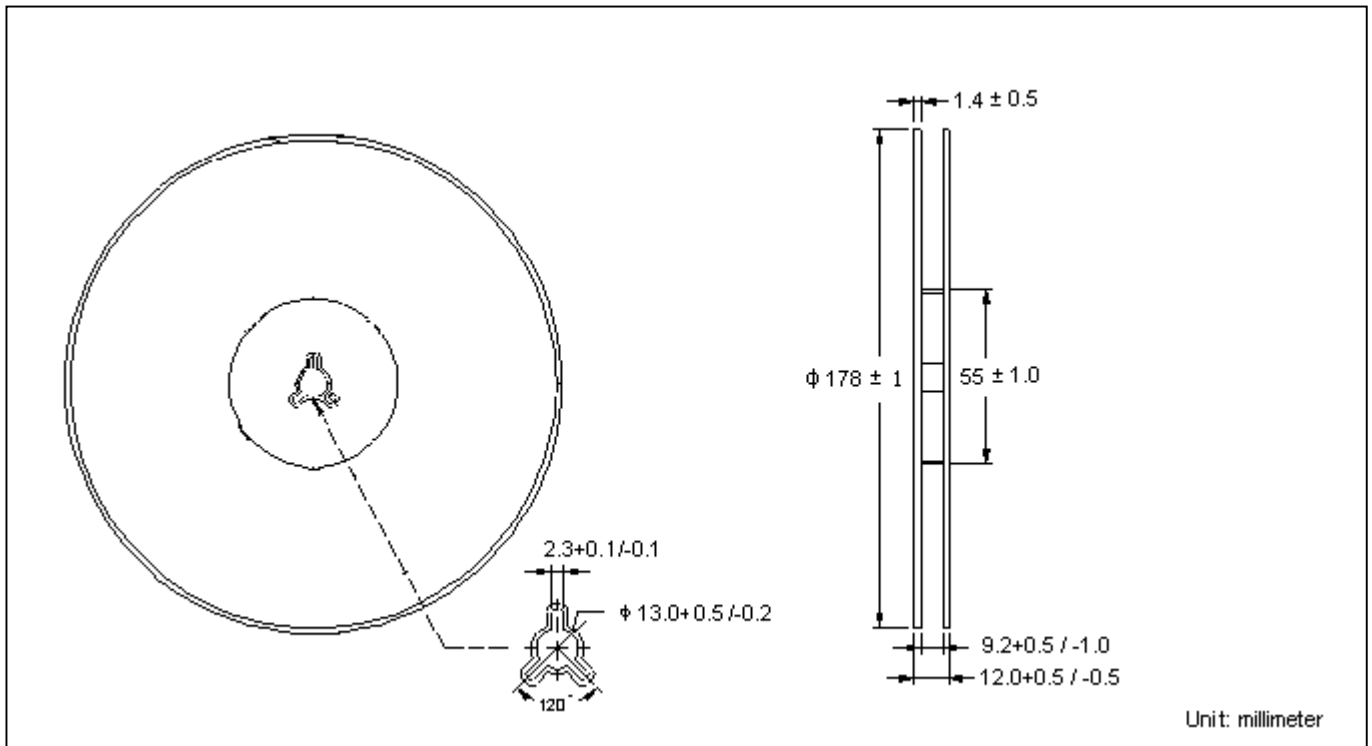
Cutoff Frequency vs Collector Current



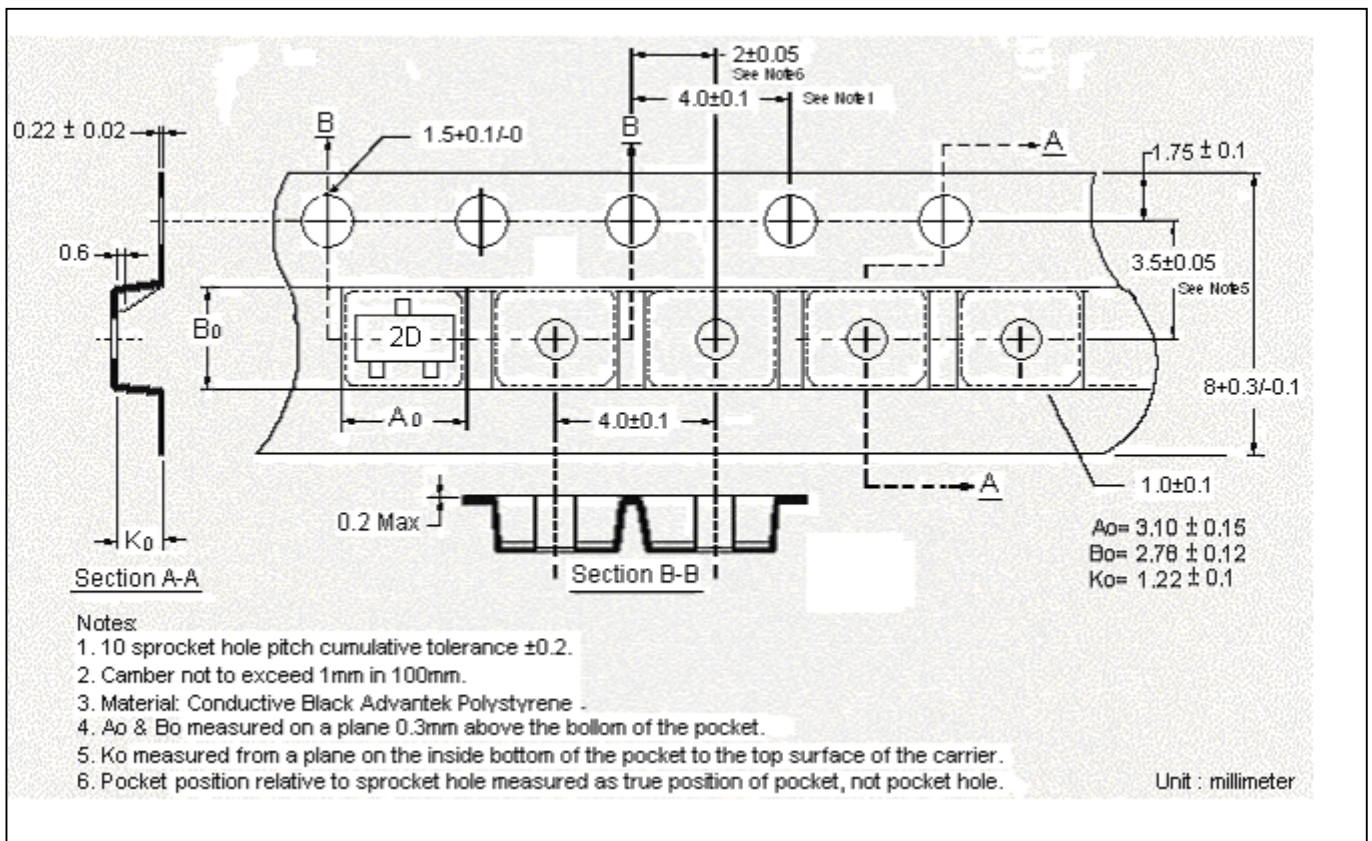
Power Derating Curve



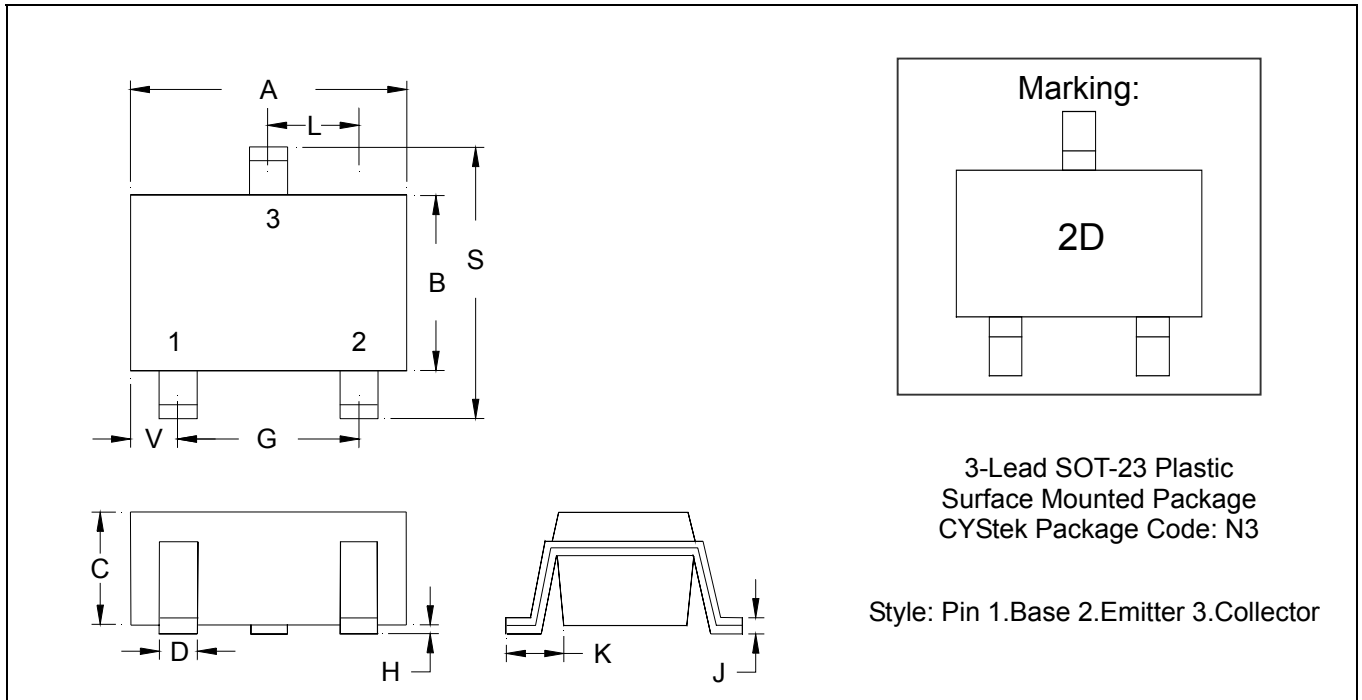
Reel Dimension



Carrier Tape Dimension



SOT-23 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0034	0.0070	0.085	0.177
B	0.0472	0.0630	1.20	1.60	K	0.0128	0.0266	0.32	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1083	2.10	2.75
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0005	0.0040	0.013	0.10					

- Notes: 1. Controlling dimension: millimeters.
 2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: 42 Alloy ; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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